INTEGRATED CIRCUITS

DATA SHEET

74LVT2413.3V Octal buffer/line driver (3-State)

Product specification Supersedes data of 1996 May 29 IC23 Data Handbook





3.3V Octal buffer/line driver (3-State)

74LVT241

FEATURES

- Octal bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Power-up 3-State
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model.

DESCRIPTION

The 74LVT241 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74LVT241 device is an octal buffer that is ideal for driving bus lines. The device features two Output Enables (1 $\overline{\text{OE}}$, 2OE), each controlling four of the 3-State outputs.

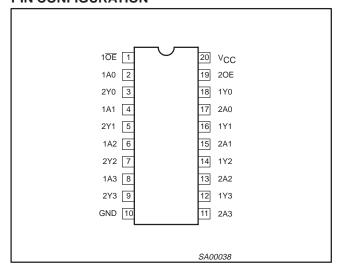
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	$C_L = 50pF;$ $V_{CC} = 3.3V$	2.8 2.8	ns
C _{IN}	Input capacitance	V _I = 0V or 3.0V	4	pF
C _{OUT}	Output capacitance	Outputs disabled; V _O = 0V or 3.0V	8	pF
I _{CCZ}	Total supply current	Outputs disabled; V _{CC} = 3.6V	0.12	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic SOL	-40°C to +85°C	74LVT241 D	74LVT241 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to +85°C	74LVT241 DB	74LVT241 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVT241 PW	74LVT241PW DH	SOT360-1

PIN CONFIGURATION



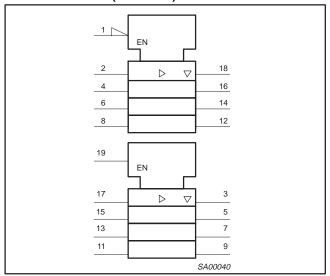
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 4, 6, 8	1A0 – 1A3	Data inputs
17, 15, 13, 11	2A0 – 2A3	Data inputs
18, 16, 14, 12	1Y0 – 1Y3	Data outputs
3, 5, 7, 9	2Y0 – 2Y3	Data outputs
1, 19	1 0E , 20E	Output enables
10 GND		Ground (0V)
20	V _{CC}	Positive supply voltage

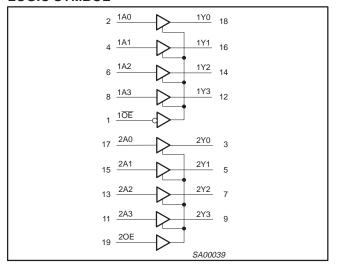
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LOGIC SYMBOL (IEEE/IEC)



LOGIC SYMBOL



FUNCTION TABLE

	INP	OUTPUTS			
10E	1An	20E	2An	1Yn	2Yn
L	L	Н	L	L	L
L	Н	Н	Н	Н	Н
Н	Х	L	Х	Z	Z

H = High voltage level

= Low voltage level

X = Don't careZ = High impedance "off" state

ABSOLUTE MAXIMUM RATINGS1, 2

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT	
V _{CC}	DC supply voltage		-0.5 to +4.6	V	
VI	DC input voltage ³		−0.5 to +7.0	V	
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V	
	DC output ourrent	Output in Low state	128	A	
Гоит	DC output current	Output in High state	-64	mA	
I _{IK}	DC input diode current	V _I < 0	-50	mA	
l _{ok}	DC output diode current	V _O < 0	-50	mA	
T _{stg}	Storage temperature range		-65 to 150	°C	

- 1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	ITS	UNIT
STWIBOL	TANAMETER	MIN	MAX	ONIT
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level Input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
la	Low-level output current		32	mA
loL	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		64	ША
Δt/Δν	Input transition rise or fall rate; outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

DC ELECTRICAL CHARACTERISTICS

					LIMITS		UNIT
SYMBOL	PARAMETER	TEST CONDITIONS	i	T _{amb} =	-40°C to -	+85°C	
				MIN	TYP ¹	MAX	1
V _{IK}	Input clamp voltage	$V_{CC} = 2.7V; I_I = -18mA$		0.9	-1.2	V	
		$V_{CC} = 2.7 \text{ to } 3.6\text{V}; I_{OH} = -100\mu\text{A}$		V _{CC} -0.2	V _{CC} -0.1		V
V _{OH} High-level output voltage		$V_{CC} = 2.7V; I_{OH} = -8mA$		2.4	2.5		V
		$V_{CC} = 3V$; $I_{OH} = -32mA$		2	2.2		V
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.1	0.2	
		V _{CC} = 2.7V; I _{OL} = 24mA			0.3	0.5	1
V_{OL}	Low-level output voltage	V _{CC} = 3V; I _{OL} = 16mA			0.25	0.4	V
	$V_{CC} = 3V$; $I_{OL} = 32mA$			0.3	0.5	1	
		V _{CC} = 3V; I _{OL} = 64mA		0.4	0.55	1	
		$V_{CC} = 0 \text{ or } 3.6V; V_I = 5.5V$			1	10	
1.	I _I Input leakage current	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND	Control pins		±0.1	±1	μA
"	Imput leakage current	$V_{CC} = 3.6V; V_I = V_{CC}$	Data pins ⁴		0.1	1] μΛ
		$V_{CC} = 3.6V; V_I = 0$	Βαία βίπο		-1	-5]
I_{OFF}	Output off current	$V_{CC} = 0V$; V_I or $V_O = 0$ to 4.5V			1	±100	μА
		$V_{CC} = 3V; V_I = 0.8V$		75	150		μΑ
I_{HOLD}	Bus Hold current A inputs ⁶	$V_{CC} = 3V; V_I = 2.0V$		- 75	-150		
		$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$		±500			
I_{EX}	Current into an output in the High state when V _O > V _{CC}	$V_{O} = 5.5V; V_{CC} = 3.0V$			60	125	μΑ
I _{PU/PD}	Power up/down 3-State output current ³	$V_{CC} = \le 1.2V$; $V_O = 0.5V$ to V_{CC} ; $V_I = 0$ OE/OE = Don't care	GND or V _{CC} ;		±1	±100	μА
I _{OZH}	3-State output High current	$V_{CC} = 3.6V; V_{O} = 3.0V$			1	5	μΑ
I _{OZL}	3-State output Low current	$V_{CC} = 3.6V; V_{O} = 0.5V$			-1	- 5	μΑ
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ o		0.12	0.19		
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or		3	12	mA	
I _{CCZ}	1	$V_{CC} = 3.6V$; Outputs Disabled; $V_I = GN$	ID or V_{CC} , $I_O = 0^5$		0.12	0.19	1
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3.0 to 3.6V; One input at V_{CC} -0 Other inputs at V_{CC} or GND	6V;		0.1	0.25	mA

- All typical values are at T_{amb} = 25°C.
 This is the increase in supply current for each input at V_{CC} -0.6V.
 This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From V_{CC} = 1.2V to V_{CC} = 3.3V ± 10% a transition time of 100µsec is permitted. This parameter is valid for T_{amb} = 25°C only.
 Unused pins at V_{CC} or GND

- 5. I_{CCZ} is measured with outputs pulled to V_{CC} or GND.
 6. This is the bus hold overdrive current required to force the input to the opposite logic state.

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AC CHARACTERISTICS

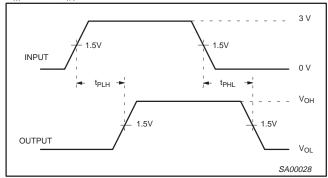
GND = 0V; $t_R = t_F = 2.5 ns; C_L = 50 pF; R_L = 500 \Omega; T_{amb} = -40 ^{\circ}C to +85 ^{\circ}C.$

				L	IMITS		
SYMBOL	PARAMETER	WAVEFORM	T _{amb} V _C	= -40° C to + C = +3.3V ± 0 .	85°C 3V	V _{CC} = 2.7V	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay nAx to nYx	1	1 1	2.8 2.8	3.8 3.8	4.0 4.0	ns
t _{PZH}	Output enable time to High and Low level 1OE to 1Y _n	2	1 1	3.2 3.1	4.4 4.3	5.0 4.9	ns
t _{PHZ}	Output disable time from High and Low level 10E to 1Y _n	2	2 1.6	3.6 2.9	5.2 4.2	5.4 4.3	ns
t _{PZH}	Output enable time to High and Low level 2OE to 2Y _n	2	1	3.8 3.8	5.1 5.0	5.6 5.4	ns
t _{PHZ}	Output disable time from High and Low level 2OE to 2Y _n	2	1	3.1 2.8	4.5 4.0	5.0 4.3	ns

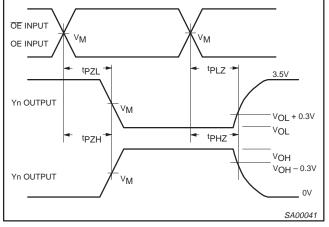
NOTE:

AC WAVEFORMS

 $V_M = 1.5V$, $V_{IN} = GND$ to 3.0V



Waveform 1. Input (An) to Output (Yn) Propagation Delays



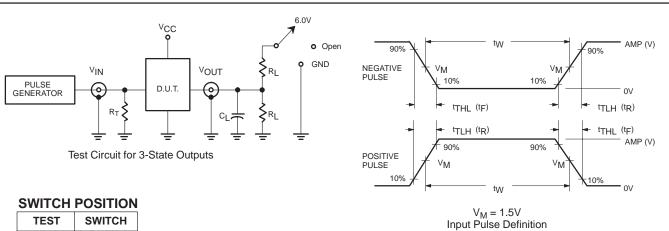
Waveform 2. 3-State Output Enable and Disable Times

^{1.} All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

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TEST CIRCUIT AND WAVEFORMS



TEST	SWITCH
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	6V
t _{PHZ} /t _{PZH}	GND

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

 C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $\label{eq:RT} \begin{aligned} R_T = & & \text{Termination resistance should be equal to } Z_{OUT} \text{ of } \\ & & \text{pulse generators.} \end{aligned}$

FAMILY	IN	PUT PULSE R	EQUIRE	MENTS	
FAMILI	Amplitude	Rep. Rate	t _W	t _R	t _F
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns

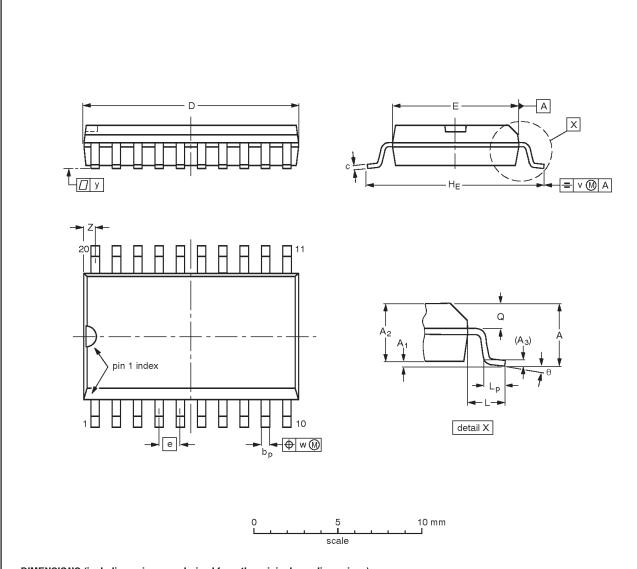
SV00092

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bp	O	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	œ	٧	w	у	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.42 0.39	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

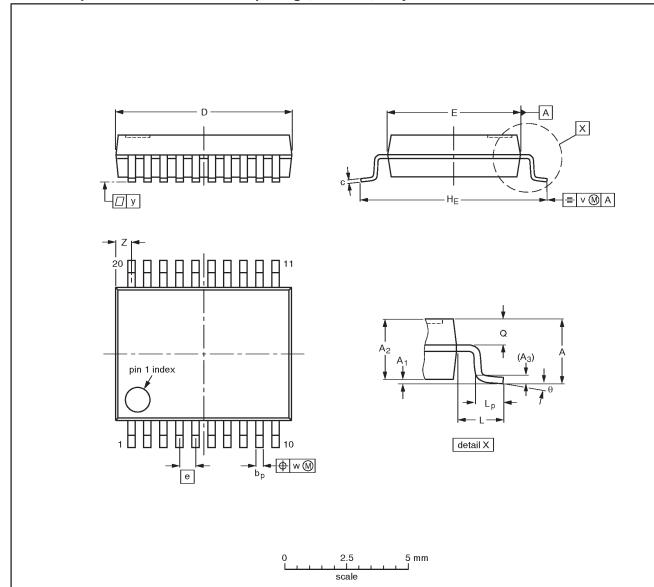
OUTLINE		REFER	RENCES	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	1330E DATE
SOT163-1	075E04	MS-013AC			-92-11-17 95-01-24

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	Α1	A ₂	A ₃	bр	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Ø	v	w	у	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

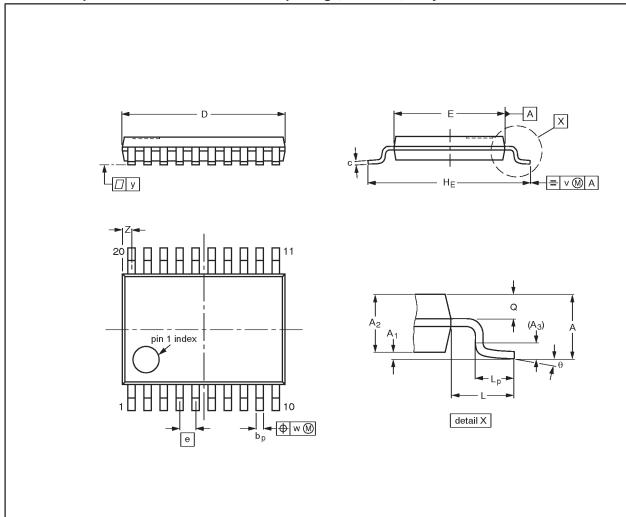
OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT339-1		MO-150AE			93-09-08 95-02-04	

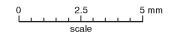
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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1





DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	рb	С	D ⁽¹⁾	E ⁽²⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUEDATE
SOT360-1		MO-153AC			-93-06-16- 95-02-04

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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